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Applications

DC/DC converters

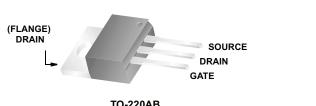
FDP8870-F085 N-Channel PowerTrench[®] MOSFET 30V, 156A, 4.1mΩ

General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{\text{DS}(\text{ON})}$ and fast switching speed.

Features

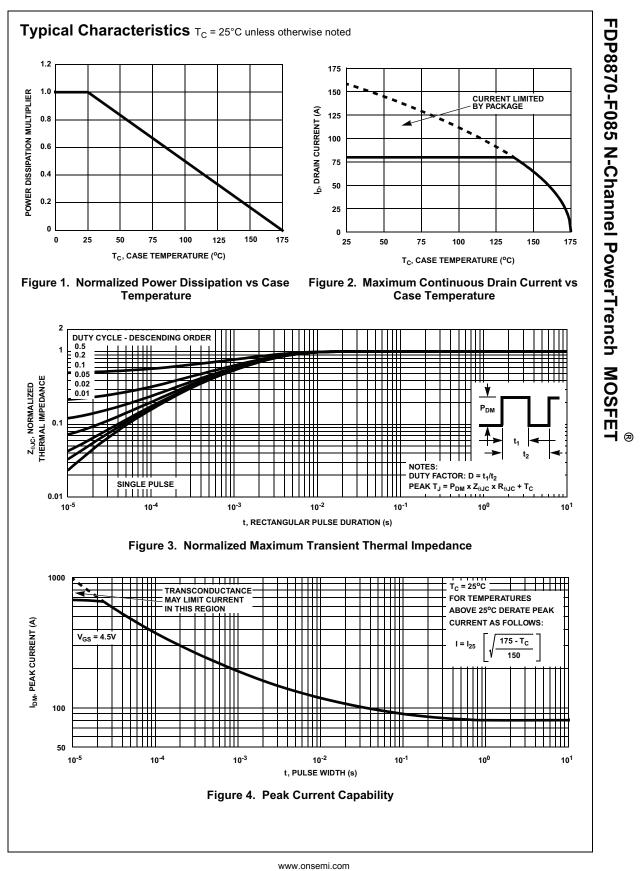
- $r_{DS(ON)} = 4.1 m\Omega$, $V_{GS} = 10V$, $I_D = 35A$
- $r_{DS(ON)}$ = 4.6m Ω , V_{GS} = 4.5V, I_D = 35A
- + High performance trench technology for extremely low $\ensuremath{^r_{\text{DS(ON)}}}$
- Low gate charge
- High power and current handling capability
- Qualified to AEC Q101
- RoHS Compliant

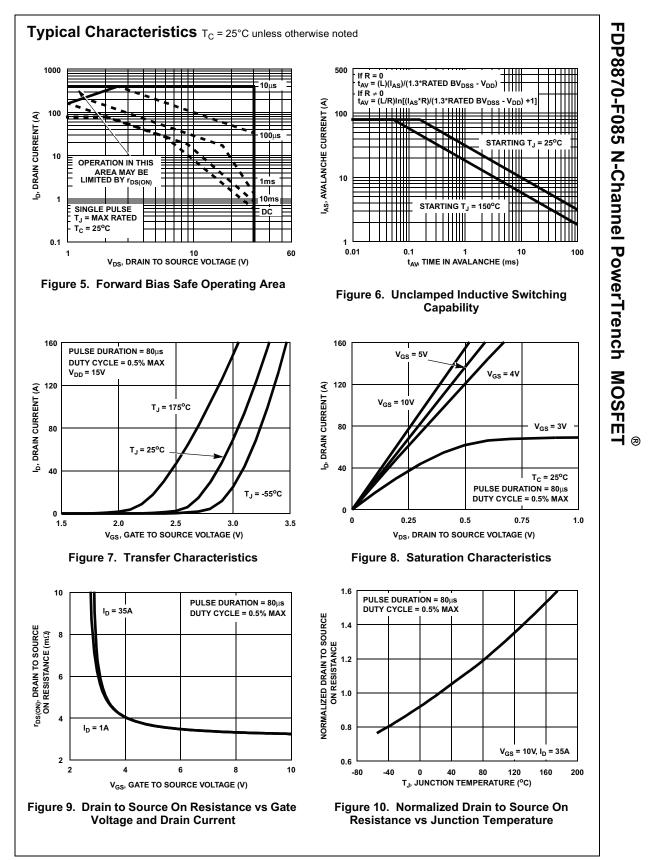


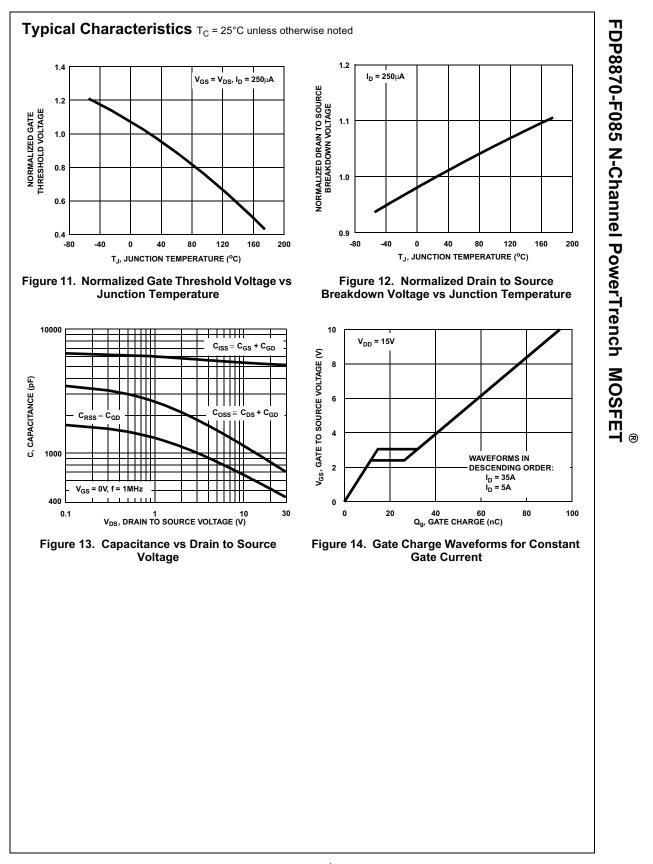


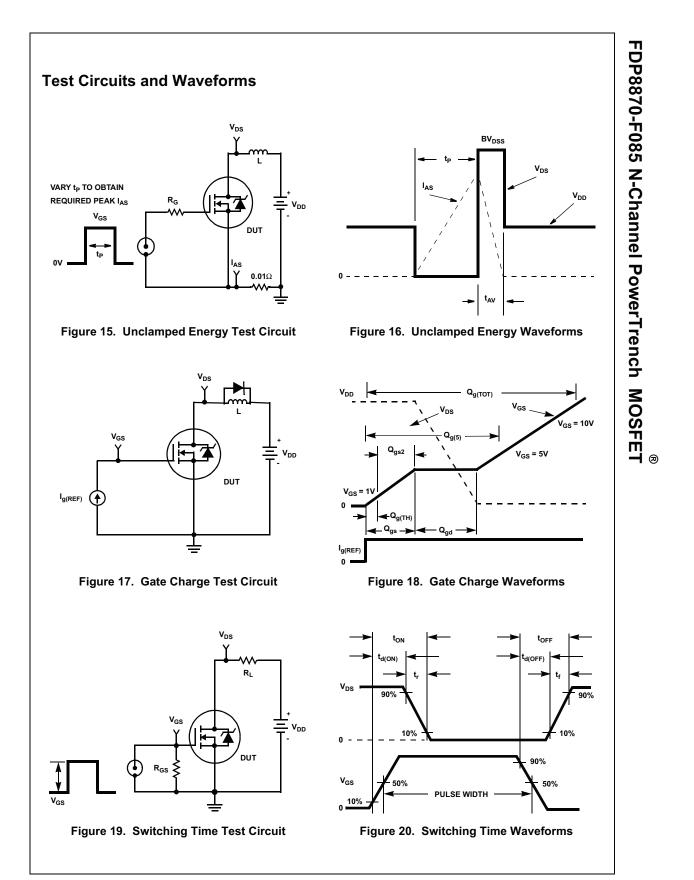
Symbol		Para	ameter		Ratings	Unit
V _{DSS}	Drain to S	ource Voltage			30	V
V _{GS}	Gate to So	ource Voltage			±20	V
	Drain Curr	ent				
	Continuou	s (T _C = 25°C, V _{GS} = 10	156	A		
I _D	Continuou	s (T _C = 25°C, V _{GS} = 4.5		147	A	
	Continuou	s (T _{amb} = 25°C, V _{GS} = 1	19	A		
	Pulsed		Figure 4	A		
E _{AS}	Single Pul	se Avalanche Energy (N	300	mJ		
PD	Power dise	sipation	160	W		
гD	Derate ab	ove 25°C			1.07	W/º0
T _J , T _{STG}	Operating	and Storage Temperatu	ire		-55 to 175	5 °C
R _{θJC} Thermal Resistance Junction to Case TO-220 R _{θJA} Thermal Resistance Junction to Ambient TO-220 (Note 3)					0.94	°C/V °C/V
Package	e Markir	ng and Ordering	· · · · · · · · · · · · · · · · · · ·	,	Tape Width	Quantity
Device Marking FDP8870		Device	TO-220AB	1/661 0126	N/A	50 units

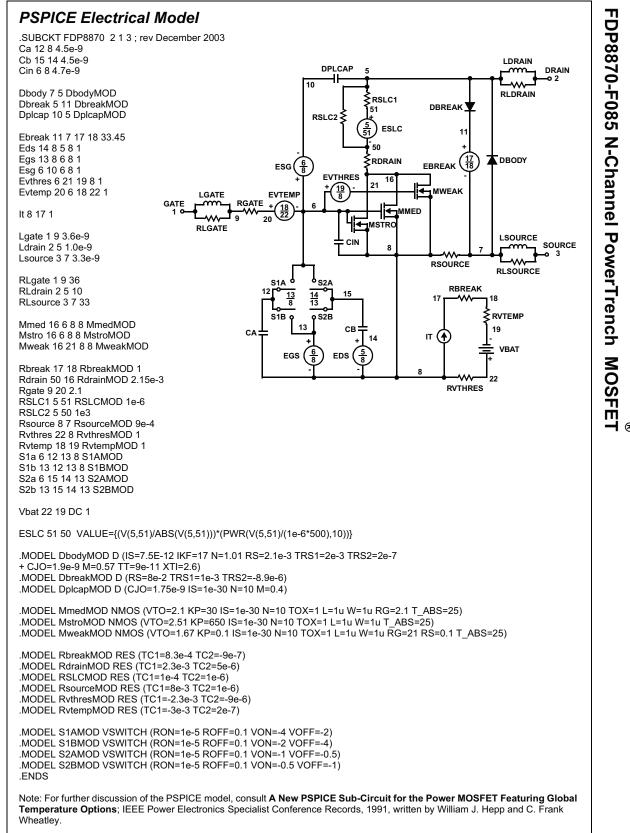
Symbol	Parameter Test Conditions		Min	Тур	Max	Uni
Off Chara	acteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	burce Breakdown Voltage $I_D = 250 \mu A, V_{GS} = 0V$		-	-	V
I _{DSS}		V _{DS} = 24V	-	- 1		
	Zero Gate Voltage Drain Current	$V_{GS} = 0V \qquad T_C = 150^{\circ}C$	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V	-	-	±100	nA
	cteristics					
V _{GS(TH)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	1.2	-	2.5	V
		I _D = 35A, V _{GS} = 10V	-	0.0034	0.0041	Ω
	Durain to Course On Desistance	I _D = 35A, V _{GS} = 4.5V	-	0.0040	0.0046	
rds(on)	Drain to Source On Resistance	I _D = 35A, V _{GS} = 10V, T _J = 175 ^o C	-	0.0051	0.0065	
Dynamic	Characteristics					
C _{ISS}	Input Capacitance		-	5200	-	pF
C _{OSS}	Output Capacitance	$-V_{DS} = 15V, V_{GS} = 0V,$	-	970	-	pF
C _{RSS}	Reverse Transfer Capacitance	f = 1MHz	-	570	-	pF
R _G	Gate Resistance	V _{GS} = 0.5V, f = 1MHz	-	2.1	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0V to 10V	-	106	132	nC
Q _{g(5)}	Total Gate Charge at 5V	$V_{GS} = 0V \text{ to } 5V$	-	56	69	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{00} = 0V \text{ to } 1V$ $V_{DD} = 15V$	-	5.0	6.5	nC
Q _{as}	Gate to Source Gate Charge	$I_D = 35A$ $I_a = 1.0mA$	-	15	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau	ig - 1.011A	-	10	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	23	-	nC
Switchin	g Characteristics (V _{GS} = 10V)					
t _{ON}	Turn-On Time		-	-	168	ns
t _{d(ON)}	Turn-On Delay Time	-	-	11	-	ns
t _r	Rise Time	V _{DD} = 15V, I _D = 35A	-	105	-	ns
t _{d(OFF)}	Turn-Off Delay Time	$V_{GS} = 4.5V, R_{GS} = 3.3\Omega$	-	70	-	ns
t _f	Fall Time		-	46	-	ns
t _{OFF}	Turn-Off Time	_	-	-	173	ns
	urce Diode Characteristics					
V _{SD}		I _{SD} = 35A	- 1	-	1.25	V
	Source to Drain Diode Voltage	I _{SD} = 15A	-	-	1.0	V
+	Reverse Recovery Time	I _{SD} = 35A, dI _{SD} /dt = 100A/μs	-	-	37	ns
t _{rr}						



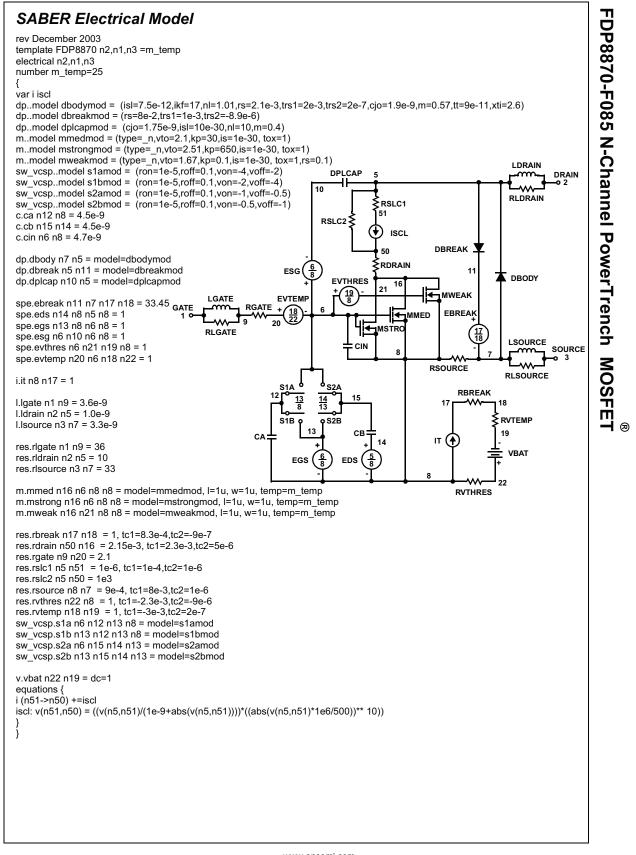


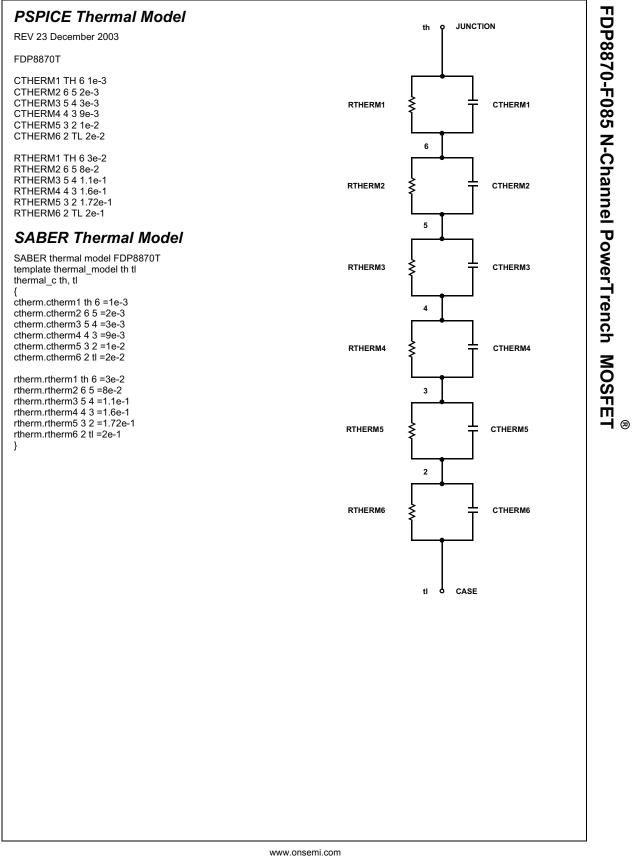






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